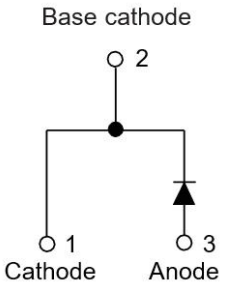
Ultra-Fast Recovery Diodes 30A FRED



Features

- High frequency operation
- High surge forward current capability
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Solder dip 275 °C max. 7 s, per JESD 22-B106

Typical Applications

Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

Mechanical Data

- **Package**: TO-247AC
  Molding compound meets UL 94 V-0 flammability rating, -
- **Terminals**: Tin plated leads, solderable per J-STD-002 and JESD22-B102
- **Polarity**: As marked

■Maximum Ratings (T_j=25℃ Unless otherwise specified）

PARAMETER	SYMBOL	UNIT	MUR30120PL
Device marking code			MUR30120PL
Repetitive Peak Reverse Voltage	V_{RRM}	V	1200
Average Rectified Output Current @60Hz half sine-wave, R-load, Tc(FIG.1)	I_O	A	30
Surge(Non-repetitive)Forward Current @60Hz half sine-wave, 1 cycle, T_j=25℃	I_{FSM}	A	210
Current Squared Time @1ms≤t≤8.3ms Tj=25℃	I^2t	A^2s.	183
Single Pulse Avalanche Energy @ Tp=40uS, Tj=25℃,L=15mH	EAS	mJ	2.7
Storage Temperature	T_{stg}	℃	-55 ~ +175
Junction Temperature	Tj	℃	-55 ~ +175
Typical Junction capacitance @4V,1MHz	Cj	pF	97

MUR30120PL-B1-W5094HF

■Electrical Characteristics（Tj=25℃ Unless otherwise specified）

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS		Min	Typ	Max
instantaneous forward voltage drop per diode	VFM	V	IFM=30.0A Tj=25℃		-	2.8	3.3
			IFM=30.0A Tj=125℃		-	2.1	2.8
DC reverse current at rated DC blocking voltage per diode	IRRM1	uA	VRM=VRRM Tj=25℃		-	-	5.0
	IRRM2		VRM=VRRM Tj=125℃		-	-	200
Reverse Recovery Time	Trr	ns	I_F=0.5A I_{RM}=1A I_{RR}=0.25A Tj=25℃		-	38	70
			Tj=25℃	I_F=30A di/dt=-200A/us V_{RM}=960V	-	206	-
			Tj=125℃		-	255	-
Peak recovery current	I_{RRM}	A	Tj=25℃		-	4.25	-
			Tj=125℃		-	9.10	-
Reverse recovery charge	Qrr	nC	Tj=25℃		-	434	-
			Tj=125℃		-	1713	-

■Thermal Characteristics （Tj=25℃ Unless otherwise specified）

PARAMETER		SYMBOL	UNIT	MUR30120PL
Thermal Resistance	Between junction and case	$R_{\theta J-C}$	℃/W	0.4

■Ordering Information (Example)

PREFERED P/N	UNIT WEIGHT(g)	MINIIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
MUR30120PL	Approximate 6.0	30	360	1800	Tube

■Characteristics (Typical)

FIG1:Io -Tc Curve

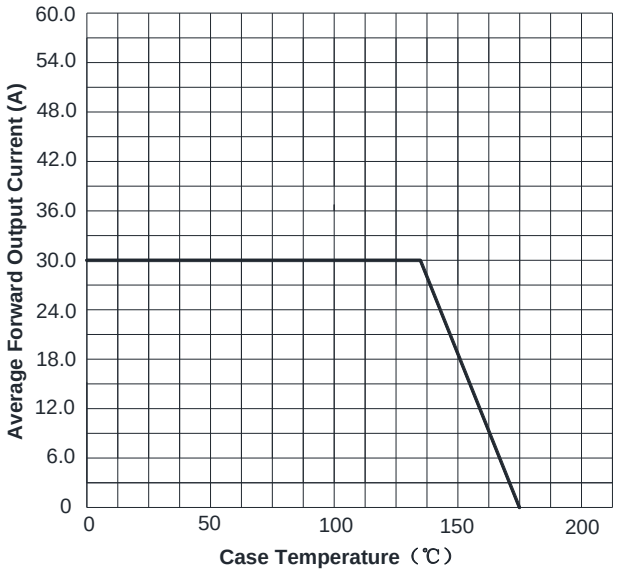


FIG2:Surge Forward Current Capability

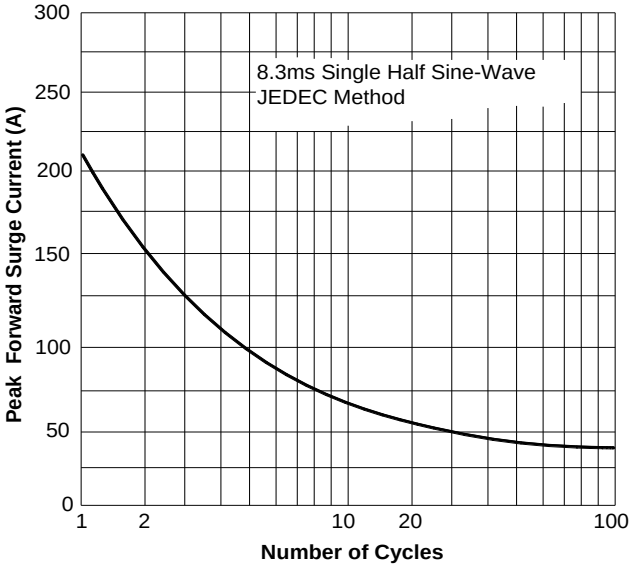


FIG3: Forward Voltage

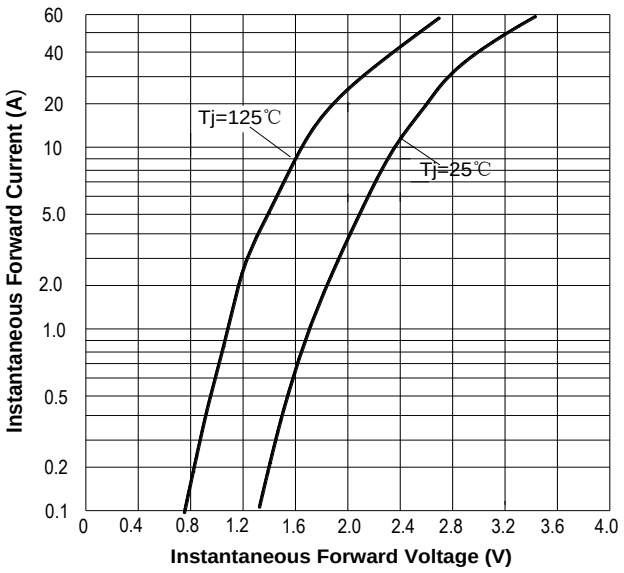


FIG4: Typical Reverse Characteristics

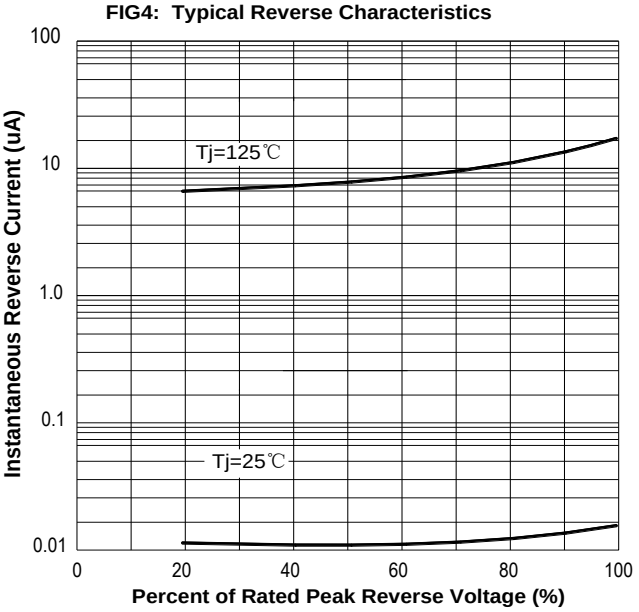
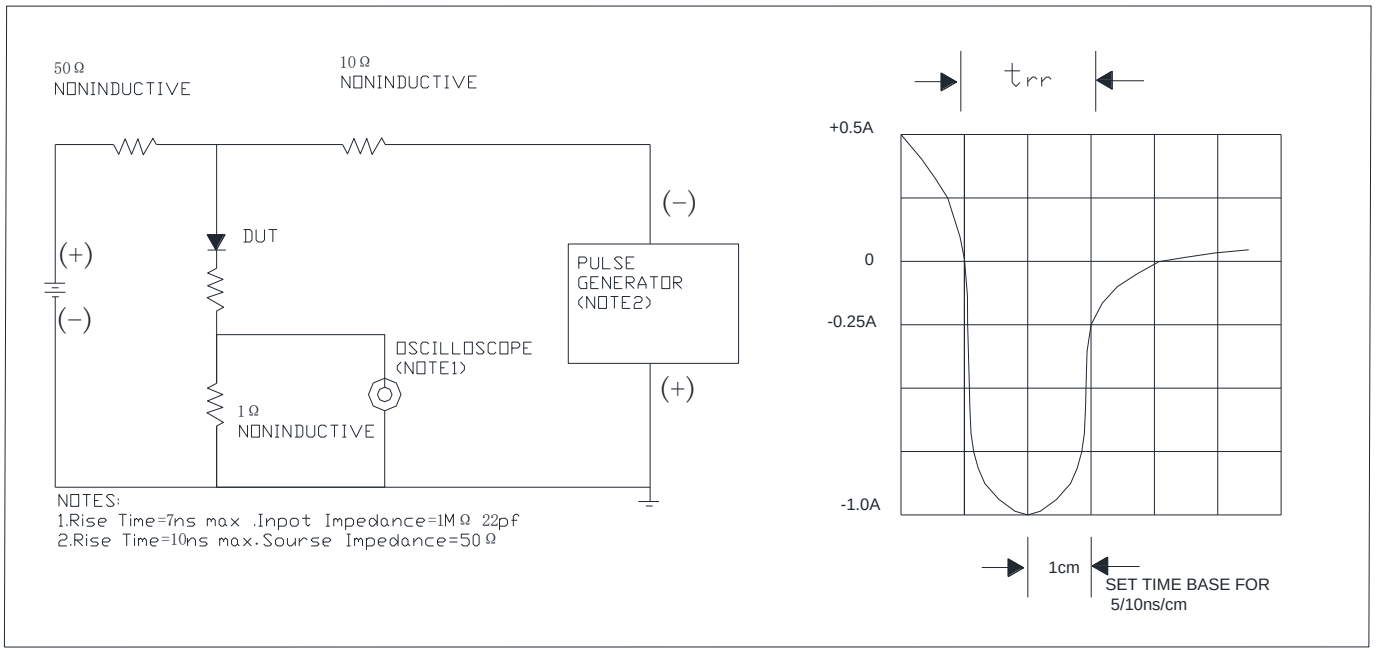
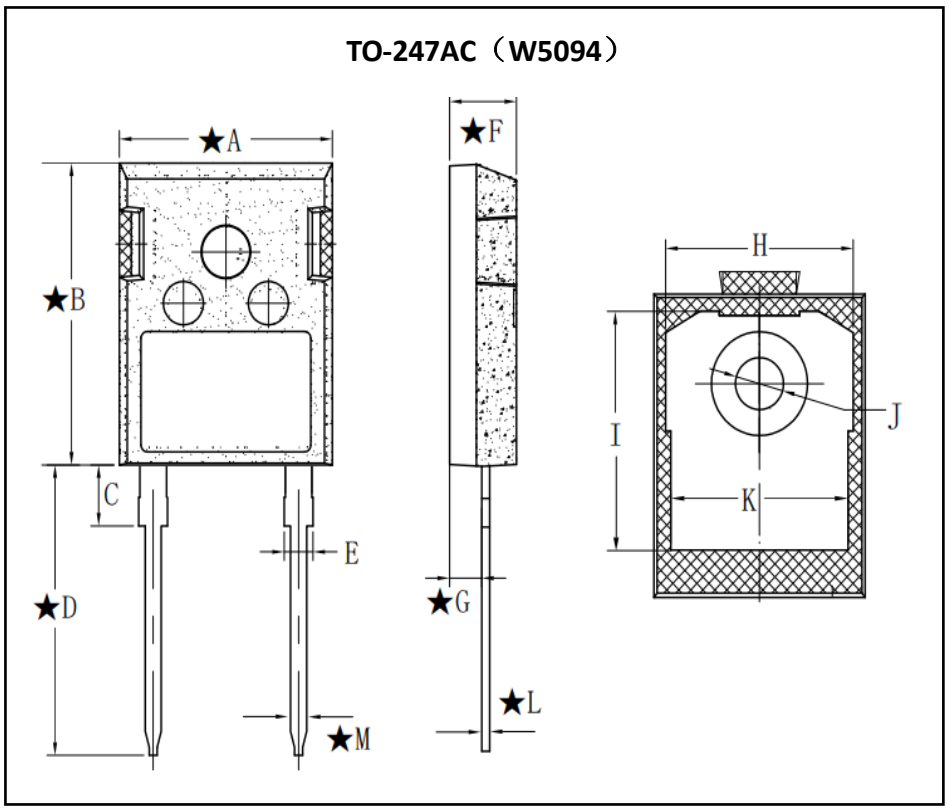


FIG.5 Diagram of circuit and Testing wave form of reverse recovery time



■ Outline Dimensions



TO-247AC		
Dim	Min	Max
A	15.72	16.12
B	20.7	21.1
C	4.02	4.42
D	19.9	20.3
E	2.0	2.3
F	4.8	5.2
G	2.3	2.5
H	TYP 14.02	
I	TYP 16.55	
J	3.5	3.7
K	TYP 13.26	
L	0.58	0.62
M	1.15	1.25

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